

## METHYL FORMATION FROM METHANOL DECOMPOSITION ON Pd{111} AND Pt{111}

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Received 15 July 1988; accepted 30 September 1988

The decomposition of  $\text{CH}_3\text{OH}$  adsorbed on Pd{111} and Pt{111} is compared as the surface is heated between 100 and 500 K. Using secondary ion mass spectrometry (SIMS) and thermal programmed desorption (TPD) it is suggested that an anomalous  $\text{CH}_3^+$  ion signal observed previously by Akhter and White on oxygen precovered Pt{111} arises from the formation of a surface  $\text{CH}_3$  species resulting from activation of the C-O bond of  $\text{CH}_3\text{OH}$ . This interpretation stems from a recent observation by Levis, Zhicheng and Winograd that  $\text{CH}_3\text{OH}$  decomposes to  $\text{CH}_3$ , OH and  $\text{OCH}_3$  on clean Pd{111} between 100 and 300 K. The results are discussed in terms of the relative ability of these metals to synthesize  $\text{CH}_3\text{OH}$  from CO and  $\text{H}_2$ .

Secondary ion mass spectrometry (SIMS) has recently been applied towards elucidating the surface chemistry of  $\text{CH}_3\text{OH}$  adsorbed on oxygen precovered Pt{111} [1] and clean Pd{111} [2] between 100 and 400 K. For both systems, the positive ion observed at  $m/e$  15, assigned to  $\text{CH}_3^+$ , is detected as a function of surface temperature and is related to the  $\text{CH}_3\text{OH}_{\text{ads}}$  thermal decomposition reaction mechanism. Thermal programmed desorption (TPD) and SIMS studies of  $\text{CH}_3\text{OH}$  adsorbed on O/Pt{111} suggest that  $\text{CH}_3\text{OH}_{\text{ads}}$  decomposes to  $\text{CH}_3\text{O}_{\text{ads}}$  (methoxide) from 116 K to 140 K and that further heating causes decomposition to CO and  $\text{H}_2$ . On Pd{111}, X-ray photoelectron spectroscopic (XPS) and SIMS measurements suggest that  $\text{CH}_3\text{OH}_{\text{ads}}$  decomposes to  $\text{CH}_{3\text{ads}}$ ,  $\text{CH}_3\text{O}_{\text{ads}}$  and  $\text{H}_2\text{O}_{\text{ads}}$  above 175 K, and that further decomposition to CO and  $\text{H}_2$  occurs above 350 K. In light of the study, an anomalous increase in the  $\text{CH}_3^+$  SIMS intensity vs. temperature plot for certain  $\text{CH}_3\text{OH}$  coverages reported in the Pt{111} investigation can be attributed to the formation of a  $\text{CH}_3$  species. The production and stability of  $\text{CH}_{3\text{ads}}$  on each surface may have implications in the relative catalytic properties of Pd and Pt based catalysts.

A critical contribution from the investigation on O/Pt{111} is that the transformation from  $\text{CH}_3\text{OH}_{\text{ads}}$  to  $\text{CH}_3\text{O}_{\text{ads}}$  can be detected using SIMS since the  $\text{CH}_3^+$  intensity from  $\text{CH}_3\text{OH}_{\text{ads}}$  is much larger than that from  $\text{CH}_3\text{O}_{\text{ads}}$ . This difference in fragmentation efficiency accounts for the pronounced decrease in the  $\text{CH}_3^+$  SIMS signal in the temperature programmed (TP) SIMS spectrum shown in figure 1a, b and c between 110 and 140 K. During the TPSIMS experiment on Pt{111} an anomalous increase in the  $\text{CH}_3^+$  signal is observed at 180 K. This signal vanishes at 220 K for initial  $\text{CH}_3\text{OH}$  exposures  $\geq 0.12$  L and does not reappear at temperatures at least up to 900 K. The anomalous increase was tentatively assigned to a change in the ionization probability of the  $\text{CH}_3^+$  SIMS signal resulting from desorption of  $\text{H}_2\text{O}$  at 180 K.

On clean Pd{111} recent SIMS and XPS measurements of the  $\text{CH}_3\text{OH}$  thermal decomposition reaction from 110 K to 400 K have shown that  $\text{CH}_{3\text{ads}}$ ,  $\text{H}_2\text{O}_{\text{ads}}$  and  $\text{CH}_3\text{O}_{\text{ads}}$  are formed with increasing surface temperature [2]. The XPS data, for example, show that there are two C 1s peaks of equal intensity formed at 175 K at 285.9 eV and 284.2 eV. The 285.9 eV peak is shown to arise from  $\text{OCH}_{3\text{ads}}$  by comparison to the spectra for  $\text{CH}_3\text{OH}$  adsorbed on O/Pd{111} which is known to produce  $\text{OCH}_{3\text{ads}}$  [4]. The 284.2 eV peak is assigned to  $\text{CH}_{3\text{ads}}$ . Although it is not possible to make this assignment from XPS data alone, we have shown that the intensity of this peak as a function of temperature correlates with the  $\text{CH}_3^+$  ion observed in SIMS. The direct assignment of this  $\text{CH}_3^+$  ion to  $\text{CH}_{3\text{ads}}$  is possible for a number of reasons. First, a major source of  $\text{CH}_3^+$  is from the ion-beam induced cracking of  $\text{CH}_3\text{OH}_{\text{ads}}$ . This species is gone from the surface by  $\sim 150$  K and cannot contribute to the signal. Secondly, the  $\text{CH}_3^+$  ion intensity derived from the ion-beam induced cracking of  $\text{OCH}_{3\text{ads}}$  is found to be quite small on both Pt [1] and Pd [2,3]. Note, for example, that no increase in the  $\text{CH}_3^+$  ion intensity is observed in figure 1c even though there is an extensive amount of  $\text{OCH}_{3\text{ads}}$  formation [1]. Finally, it is possible that  $\text{CH}_3^+$  ion signals could arise from recombination during desorption of  $=\text{CH}_2$  or  $\equiv\text{CH}$  surface species with  $\text{H}^+$ . The  $\text{CH}_2^+$  and  $\text{CH}^+$  ion signals must also be present in this scenario. Since the SIMS result is conspicuously missing contributions from these fragment ions, we have concluded [2,3] that the only possible assignment for the large  $m/e$  15 intensity and for the 284.2 eV C 1s peak after desorption and decomposition of  $\text{CH}_3\text{OH}$  is to  $\text{CH}_{3\text{ads}}$ .

With these assignments in hand, it is of value to compare the behavior of the  $m/e$  15 peak for  $\text{CH}_3\text{OH}$  decomposition on Pd{111} to that found for Pt{111} between 110 and 400 K. For a 1 L  $\text{CH}_3\text{OH}$  exposure on Pd{111}, as shown in fig. 1d, the  $\text{CH}_3^+$  SIMS intensity initially decreases between 110 and 150 K, once again indicating decomposition to  $\text{CH}_3\text{O}_{\text{ads}}$ . Above 150 K the  $\text{CH}_3^+$  signal increases in a manner similar to the anomalous result on Pt{111}. The  $\text{CH}_3^+$  intensity reaches a maximum at 200 K. The subsequent decrease between 200 and 300 K is due in part to a gradual removal of surface species,  $\approx 15\%$  by 300 K, by the primary ion beam. On the Pd{111} surface the increase in the  $\text{CH}_3^+$  signal is

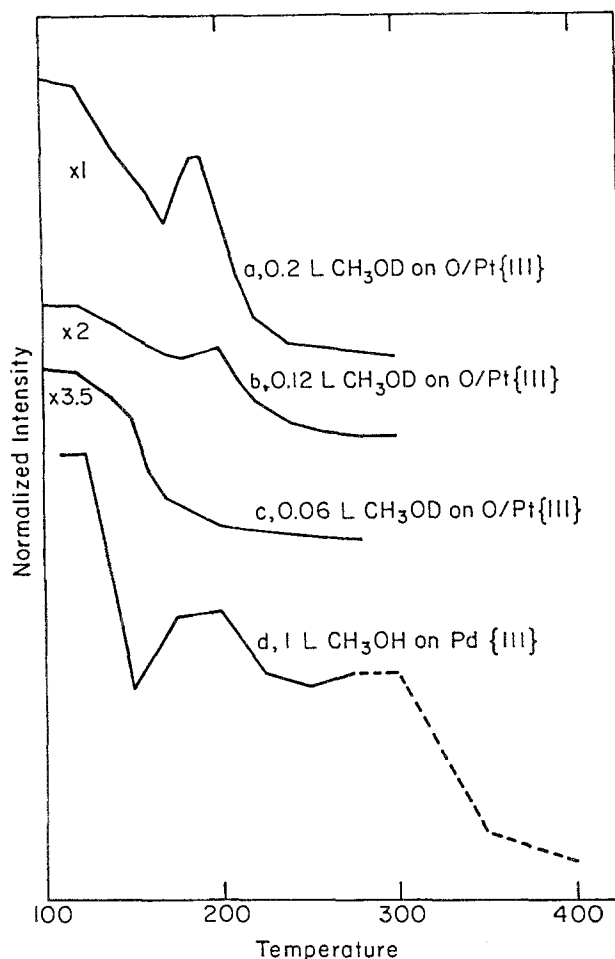


Fig. 1. Plots of the  $\text{CH}_3^+$  ion intensity as a function of surface temperature for a) 0.20 L  $\text{CH}_3\text{OD}$ , b) 0.12 L  $\text{CH}_3\text{OD}$ , c) 0.06 L  $\text{CH}_3\text{OD}$  adsorbed at 100 K on 0.25 ML O on Pt{111}. The primary ion current was 1 nA and the heating rate was  $1.1 \text{ K sec}^{-1}$ . d) A plot of the  $\text{CH}_3^+$  ion intensity as a function of temperature for a 1 L exposure of  $\text{CH}_3\text{OH}$  adsorbed at 110 K on Pd{111}. The dotted line is taken from an experiment of similar exposure at 130 K which was heated immediately to 273 K. For this plot, an entire SIMS spectrum is recorded, the temperature is then ramped 25 K and another spectrum is recorded. The primary ion current was  $2.0 \text{ nA cm}^{-2}$  and the beam energy was 3 keV.

not followed by the same substantial decrease at 220 K as on the Pt{111} surface. Rather, the  $\text{CH}_3$  ion intensity slowly decreases until above 300 K, where  $\text{CH}_{3\text{ads}}$  presumably begins to decompose to  $\text{C}_{\text{ads}}$ . Further heating to 300 K produces no change in the C 1s spectrum, while heating to 400 K causes the doublet of peaks at 285.9 and 284.2 eV to coalesce to a single peak at 284.3 eV, most likely attributable to  $\text{C}_{\text{ads}}$ . *The results on Pd{111}, which strongly suggest the formation and detection of  $\text{CH}_{3\text{ads}}$  using SIMS, imply that the anomalous increase in the  $\text{CH}_3^+$  signal on the O/Pt{111} surface between 180 and 220 K is also due to the formation of a  $\text{CH}_3$  species.*

The possibility of producing  $\text{CH}_{3\text{ads}}$  on O/Pt{111} permits an interpretation of a second anomalous result in the TPSIMS spectra of the  $\text{CH}_3^+$  ion on O/Pt{111}. The increase in the  $\text{CH}_3^+$  intensity between 180 K and 220 K shown in fig. 1a, b and c demonstrate a dependence on the initial  $\text{CH}_3\text{OD}$  exposure. The amount of the anomalous  $\text{CH}_3^+$  intensity is proportional to the  $\text{CH}_3\text{OH}_{\text{ads}}$  to  $\text{O}_{\text{ads}}$  ratio, or put another way, increasing the  $\text{CH}_3\text{OD}$  exposure increases the amount of  $\text{CH}_3^+$  ion observed between 180 K and 200 K. This suggests that a certain amount of  $\text{CH}_3\text{OD}_{\text{ads}}$  will titrate all of the available O sites, and that excess  $\text{CH}_3\text{OD}_{\text{ads}}$ , possibly bound to clean Pt sites, will then dissociate at the CO bond to form  $\text{CH}_{3\text{ads}}$  and  $\text{OD}_{\text{ads}}$ . This is consistent with the notion that O sites enhance the formation of  $\text{CH}_3\text{O}$  [5–10] and with the result on Pd{111} suggesting that the clean surface may promote the activation of the methanolic CO bond. A similar titration of the O sites on O/Pd{111} is suggested by an inverse relationship between the C 1s XPS signal at 284.2 eV, which denotes  $\text{CH}_{3\text{ads}}$  formation, and the initial O coverage [3].

In conclusion, we consider the relative stability of the  $\text{CH}_3$  species on Pt{111} and Pd{111}. The  $\text{CH}_3$  adsorbate decomposes at 220 K on the Pt{111} surface while on the Pd{111} surface the adsorbate is stable at least until 325 K. The XPS and SIMS experiments on the decomposition of  $\text{CH}_3\text{OH}$  on O/Pd{111} [3] demonstrate that once formed, the  $\text{CH}_3$  adsorbate has a stability which is virtually identical to  $\text{CH}_{3\text{ads}}$  on the clean surface. This suggests that the decomposition temperature for  $\text{CH}_{3\text{ads}}$  formed on O/Pt{111} approximates that found on the clean Pt{111}. We conclude that the  $\text{CH}_3$  species is not as stable on Pt{111} as on Pd{111} which may correlate to the relative catalytic properties of these two metals. A stabilized  $\text{CH}_{3\text{ads}}$  hydrocarbon fragment on the Pd{111} surface may explain the ability of pure Pd catalysts [11] to produce only  $\text{CH}_3$  containing species such as  $\text{CH}_3\text{H}$ ,  $\text{CH}_3\text{OH}$ ,  $\text{CH}_3\text{CH}_3$ , and  $\text{CH}_3\text{OCH}_3$  from CO and  $\text{H}_2$  feed gases from the combination of  $\text{CH}_{3\text{ads}}$  with  $\text{H}_{\text{ads}}$ ,  $\text{OH}_{\text{ads}}$ ,  $\text{CH}_{3\text{ads}}$  and  $\text{OCH}_{3\text{ads}}$ , respectively. In addition, the lower stability of the  $\text{CH}_3$  fragment on the Pt surface may correspond with the order of magnitude lower  $\text{CH}_3\text{OH}$  production rate on Pt catalysts when compared to Pd catalysts [12]. It would be of interest to use SIMS to determine the relative thermal stability of the methyl adsorbate on Ir{111}, which is comparable to Pt in  $\text{CH}_3\text{OH}$  production [12], and Ni{111}, which produces no  $\text{CH}_3\text{OH}$  from CO and  $\text{H}_2$  precursors. We believe that the combination of SIMS with quantitative surface techniques is particularly powerful for the pursuit of relatively complex adsorbate/metal decomposition mechanisms.

### Acknowledgments

The authors are grateful to the National Science Foundation and the Office of Naval Research for the financial support of this work.

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